NSN 5962-00-236-8192

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.660 inches and 0.785 inches
Body Width:
Between 0.220 inches and 0.280 inches
Body Height:
Between 0.140 inches and 0.180 inches
Maximum Power Dissipation Rating:
325.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and edge triggered and positive outputs and presettable and programmable and synchronous and
w/clear and w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
8 input
Case Outline Source And Designator:
T0-116 joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Memory Device Type:
Rom
Test Data Document:
95750-17007016 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:

Fiig:

A458a0

Yes - demil/mli